## Part Number: BZX84CxxTS-p-F (Date Code 0740+) Weight (mg): 6

## p = package designator See Data Sheet

XX= 10, 11, 12, 13, 15, 16, 18, 20, 22, 24, 27, 2V4, 2V7 30 33 36 39 3V0 3V3 3V6 3V9 4V3

2V7, 30, 33, 36, 39, 3V0, 3V3, 3V6, 3V9, 4V3,

| Element             | Material Group  | Materials      | CAS (if<br>applicable) | Average mass<br>homogeneous<br>Materal(%) |        | Mass (mg) | ppm<br>Homogeneous<br>Material | ppm overall |
|---------------------|-----------------|----------------|------------------------|---|--------|-----------|--------------------------------|-------------|
| Chip                | Silicon w/Metal | Doped Silicon* | 7440-21-3              | 100.00%                                   | 1.98%  | 0.1142    | 1000000                        | 1975        |
| Leadframe           | Alloy 42        | Fe             | 7439-89-6              | 57.65%                                    | 33.98% | 1.9641    | 576500                         | 19591       |
|                     |                 | Ni             | 7440-02-0              | 41.00%                                    |        |           | 410000                         | 13932       |
|                     |                 | Mn             | 7439-96-5              | 0.60%                                     |        |           | 6000                           | 203         |
|                     |                 | Cr(not Cr 6+)  | 7440-47-3              | 0.10%                                     |        |           | 1000                           | 34          |
|                     |                 | Со             | 7440-48-4              | 0.50%                                     |        |           | 5000                           | 169         |
|                     |                 | Si             | 7440-21-3              | 0.15%                                     |        |           | 1500                           | 51          |
| Leadframe Plating   | Silver          | Silver         | 7440-22-4              | 100.00%                                   | 1.05%  | 0.0606    | 1000000                        | 1048        |
| Bond Wire           | Gold Wire       | Gold           | 7440-57-5              | 100.00%                                   | 0.28%  | 0.0164    | 1000000                        | 283         |
| Encapsulation       | KTMC-1050G      | SiO2           | 60676-86-0             | 69.00%                                    | 61.47% | 3.5526    | 690000                         | 42412       |
|                     |                 | Epoxy Resin    | 29690-82-2             | 14.00%                                    |        |           | 140000                         | 8605        |
|                     |                 | Phenol Resin   | 9003-35-4              | 7.00%                                     |        |           | 70000                          | 4302        |
|                     |                 | Mg(OH)2        | 1309-42-8              | 8.00%                                     |        |           | 80000                          | 4917        |
|                     |                 | С              | 1333-86-4              | 0.20%                                     |        |           | 2000                           | 122         |
|                     |                 | others         |                        | 1.80%                                     |        |           | 18000                          | 1106        |
| Lead Plating Finish | Matte Tin       | Tin            | 7440-31-5              | 100.00%                                   | 1.24%  | 0.0718    | 1000000                        | 1242        |
|                     |                 |                |                        | Total                                     | 100.00 | 5.7797    |                                | 100000      |

## Tolerance ±10%

This data is based on information provided by our suppliers. We believe it to be correct but do not routinely validate it by measurement. It is for guidance only and Diodes Inc. does not guarantee its absolute accuracy or completeness

\* The Silicon Chip is doped at atomic levels with trace amounts of elements that may include Phosphorus, Boron, Arsenic, and other elements. Metalization may include Titanium, Nickel, Aluminum, Silver or Gold These substances are not reported where their concentration is less than the minimum reportable level per the guidelines specified in the Tables of EIA JIG-101, <u>Material Composition Declaration for Electronic Products</u>.

This product or product family does not contain any of the following substances except as CURRENTLY exempted by ELV II and RoHS and reported above:

Asbestos Azo compounds Cadmium and cadmium compounds Certain Shortchain Chlorinated Paraffins Chlorinated organic compounds Hexavalent chromium compounds Lead and lead compounds Mercury and mercury compounds Organic tin compounds Ozone Depleting Substances - Class I (CFCs, HBFCs, etc.) Ozone Depleting Substances - Class I (HCFCs) Perfluorooctane Sulphonate (**PFOS**) or related compounds Polybrominated biphenyls (**PFDS**) and Polybrominated diphenyl ethers (**PBDE**) includin**DecaBDE** Polychlorinated Biphenyls (**PCBs**) Polychlorinated Naphthalenes ( > 3 chlorine atoms) Radioactive Substances Tributyl Tin (TBT) and Triphenyl Tin (TPT) Tributyl Tin Oxide (TBTO)